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Fabricating nanopores with diameters of sub-1 nm to 3 nm using multilevel pulse-voltage injection

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To date, solid-state nanopores have been fabricated primarily through a focused-electronic beam via TEM. For mass production, however, a TEM beam is not suitable and an alternative fabrication method is required. Recently, a simple method for fabricating solid-state nanopores was reported by Kwok, H. *et al.* and used to fabricate a nanopore (down to 2 nm in size) in a membrane via dielectric breakdown. In the present study, to fabricate smaller nanopores stably—specifically with a diameter of 1 to 2 nm (which is an essential size for identifying each nucleotide)—via dielectric breakdown, a technique called “multilevel pulse-voltage injection” (MPVI) is proposed and evaluated. MPVI can generate nanopores with diameters of sub-1 nm in a 10-nm-thick Si_3N_4 membrane with a probability of 90%. The generated nanopores can be widened to the desired size (as high as 3 nm in diameter) with sub-nanometre precision, and the mean effective thickness of the fabricated nanopores was 3.7 nm.

Recently, “nanopore” technology has been attracting great attention and has become an important subject for study because of its potential to achieve label-free single-molecule DNA sequencing (i.e., direct DNA sequencing) with very high throughput at low cost^{1–27}. In addition to this advantage, another advantage, specifically, the potential to read long DNA sequences (i.e., long-read DNA sequencing), is given by direct DNA sequencing utilising nanopores. This advantage will enable the investigation of many unknown DNA markers derived from phase information²⁸. These features of direct DNA sequencing are essential for providing personalised medicine in the future; therefore, the maturation of nanopore technology has been strongly anticipated.

Nanopore technology can be broadly divided into two categories according to the constituent materials of the nanopore. One is “biological”, i.e., nanopores that are formed with biological molecules (“bio-nanopores”)^{1–7}. The other is “solid-state”, i.e., nanopores that are formed with semiconductor-related materials (“solid-state nanopores”)^{1,7–27}. The most well-known concept of DNA sequencing, common to both bio-nanopores and solid-state nanopores, detects changes in the ionic current through the nanopore during DNA translocation and identifies the four types of nucleotides from the changes in ionic current^{1–7,12–24,26,27}. To extract the ionic-current changes produced by the four types of nucleotides, the diameter of the nanopores must be on the order of that of DNA (less than 2 nm) because the differences in the molecular structures of each nucleotide are small. In addition to this requirement, to spatially discriminate each nucleotide in DNA, the thickness of the nanopores must be on the order of the distance between each nucleotide. To meet these requirements, both bio- and solid-state nanopore technologies have been developed.

In terms of biological nanopore technology, for example, the four types of nucleotides have been distinguished with high accuracies (averaging 99.8%) using an engineered α -haemolysin (α -HL) protein nanopore². Moreover, according to a recent study, ionic-current patterns through a nanopore during DNA translocation have been related to a known sequence of nucleotides using an engineered mycobacterium smegmatis porin A (MspA) nanopore with a diameter of 1.2 nm and thickness of 0.6 nm⁴.

In terms of solid-state nanopore technology, poly(dA)₃₀, poly(dC)₃₀, and poly(dT)₃₀ have been distinguished using a small nanopore (diameter of 1 to 2 nm) in a thin Si_3N_4 membrane (thickness of 5 to 8 nm)¹². In addition, graphene nanopores have been developed with the aim of ultimate single-nucleotide resolution^{18–23}, and DNA translocation through a graphene nanopore has been confirmed^{18–21}.

Solid-state nanopore technology has advantages in terms of robustness and possible large-scale integration. However, this technology suffers a serious drawback regarding the process of fabricating the nanopores. To date, focused-electron beam etching via TEM has been used to fabricate nanopores in solid-state membranes. A TEM beam can be condensed to a diameter of less than 1 nm and can thereby be used to successfully fabricate a small



nanopore with a diameter of less than 2 nm^{12,14,24,25}. For mass production, however, TEM-beam etching is not suitable because of its high cost, low throughput, and complexity. An alternative nanopore fabrication method is therefore strongly desired.

Recently, a simple method for fabricating nanopores was proposed by Kwok *et al.*²⁶. This method utilises the dielectric breakdown of a Si₃N₄ membrane in an aqueous solution to fabricate nanopores. The dielectric breakdown is caused by the strong electric field produced by two conventional Ag/AgCl electrodes, and no special setup for fabricating the nanopores is required. Nanopores with sizes as small as 2 nm were generated by the application of a high constant voltage (with a pre-determined threshold current level) to the electrodes, and the generated nanopores can be widened to the intended size by the application of pulse voltages. Ionic-current blockades were observed when double-stranded DNA (dsDNA) passed through the fabricated nanopores, and the ionic current exhibited a lower noise level compared with that of the current passing through conventional TEM-drilled nanopores. Accordingly, this fabrication method has the potential to open solid-state nanopore technology to a much greater number of researchers.

In this study, to stably fabricate nanopores with diameters of 1 to 2 nm (which is an essential size for distinguishing each nucleotide) via dielectric breakdown, a technique called “multilevel pulse-voltage injection” (MPVI) is proposed and demonstrated. Compared with Kwok’s method, MPVI uses pulse voltages for not only widening the nanopores but also for creating the nanopores, and the generation of the nanopores is verified by measuring the current through a membrane at low voltage. This method can generate nanopores with diameters of less than 1 nm in a 10-nm-thick Si₃N₄ membrane with a probability of 90%. The diameter of the generated nanopores can be widened to the desired diameters (up to 3 nm) with sub-nanometre precision. The mean effective thickness of the fabricated nanopores was 3.7 nm. These findings are derived from TEM images of the fabricated nanopores and analyses of ionic-current blockades during single-stranded DNA (ssDNA) translocation.

Results

Proposition and demonstration of MPVI. The setup for fabricating the nanopores by MPVI is illustrated in Figure 1a. Separated by a Si₃N₄ membrane with a thickness of 10 nm, two chambers (*cis* and *trans* chambers) are formed in a flowcell. Both chambers are filled with 1 M KCl aqueous solution. Two Ag/AgCl electrodes (*cis* and *trans* electrodes) are immersed in aqueous solutions and connected to a pulse-voltage generator and an ammeter.

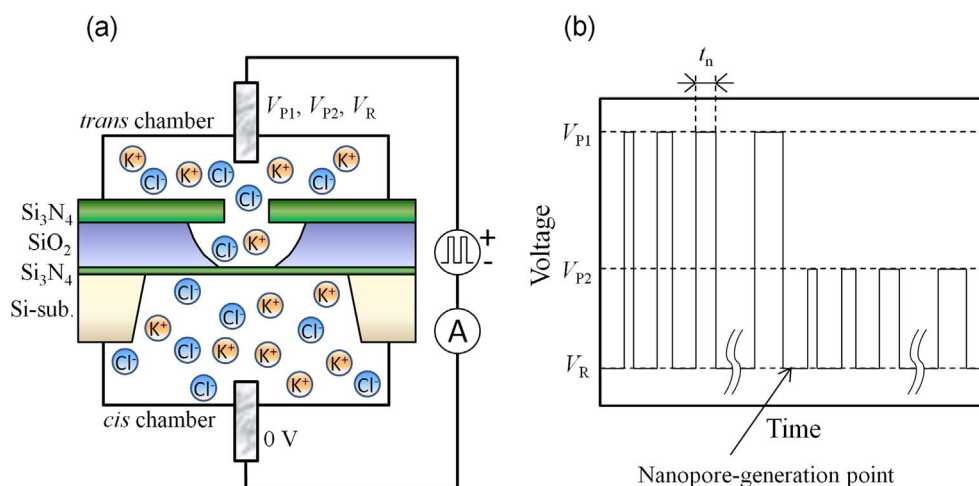


Figure 1 | Schematic diagram of MPVI. (a) Setup for MPVI. *Cis* and *trans* electrodes are immersed in both chambers and are connected to a voltage-pulse generator and an ammeter. (b) Pulse chart of MPVI, which uses three different voltages (V_{P1} , V_{P2} , and V_R). V_{P1} is used to create a nanopore. V_{P2} is used to widen the nanopore to an intended size. V_R is used to measure the current between the electrodes.

A pulse chart for MPVI is presented in Figure 1b. After a high-voltage pulse (V_{P1}) is applied between the *cis* and *trans* electrodes to generate a nanopore in the membrane, an electrical current between the electrodes at a low voltage (V_R) is measured to verify whether a nanopore is generated. If the measured current exceeds a pre-determined threshold current, it is judged that a nanopore has been generated. The nanopore-generation mechanism by MPVI is based on the dielectric breakdown induced by the high-electric-field stress, which is explained in detail by Kwok *et al.*²⁶. These authors discussed the breakdown mechanism by investigating the creation process as a function of applied voltage, membrane thickness, electrolyte composition, concentration, and pH. After the nanopore has been generated, it can be slowly widened to the intended size via the application of mid-voltage pulses (V_{P2})²⁷. The size of the nanopore can be estimated from the ionic current passing through it at low voltage (V_R).

The benefits of MPVI are explained as follows. When a voltage is applied between the *cis* and *trans* electrodes, the total electrical current ($I_{Tot.}$) between the electrodes is

$$I_{Tot.} = I_{TAT} + I_{NP}, \quad (1)$$

where I_{TAT} is the leakage current through the membrane and I_{NP} is the ionic current through the nanopore. I_{TAT} represents the non-ohmic characteristics and rapidly increases with increasing electric field strength²⁶. This behaviour is similar to that of the trap-assisted tunnelling (TAT) current in semiconductor capacitors and transistors with Si₃N₄ gate dielectrics^{29–31}. Accordingly, I_{TAT} is assumed to be primarily attributable to a TAT current due to electrons supplied from ions. In addition, I_{TAT} varies among several membranes with the same thickness and changes over time²⁶. Thus, the correct value of I_{NP} cannot be measured because of a disturbance of the time-dependent I_{TAT} fluctuation if $I_{Tot.}$ is measured at a high voltage (V_{P1}). If the correct I_{NP} cannot be measured, then a uniform threshold current value cannot be set to verify whether the nanopore is generated; i.e., if a uniform threshold current value is set, the small target size of the nanopore cannot be controlled.

In contrast to I_{TAT} , I_{NP} represents ohmic characteristics¹⁵, and the condition $I_{NP} \gg I_{TAT} \sim 0$ can be realised at a low voltage (V_R). Accordingly, MPVI is an iteration sequence composed of applied high-voltage pulses (V_{P1}) to generate or widen the nanopore and measurement of the electrical current between the electrodes at low voltage (V_R).



The dependence of I_{Tot} at V_R on the cumulated time ($t_{\text{sum.}} = \sum t_n$, where t_n is described below) of applied-pulse (V_{P1} and V_{P2}) durations is shown in Figure 2a. V_{P1} was set to 7 V. The duration of the n_{th} -pulse voltage (V_{P1}) was set as

$$t_n = 10^{-3+(1/24)(n-1)} - 10^{-3+(1/24)(n-2)} \text{ for } n \geq 2 \quad (2)$$

$$t_1 = 10^{-3} \text{ for } n = 1.$$

The number of the applied pulses (V_{P1}) per decade of time was 24, and V_R was set to 0.1 V. More detailed information about the MPVI procedure is described in Supplementary Section SI-1. Before the nanopore was generated, I_{Tot} was approximately zero at V_R . This result indicates that I_{TAT} can be neglected at V_R and that I_{NP} is free from disturbance by I_{TAT} . After the nanopore was generated, second pulse voltages ($V_{P2} = 2.5$ V) widened its diameter. A magnified part of the graph around the nanopore-generation point in Figure 2a is shown in Figure 2b. This figure illustrates that the nanopore-generation point could be detected very easily and clearly because I_{NP} is free from the disturbance by I_{TAT} .

TEM images of the fabricated nanopores with MPVI are presented in Figure 3. Notably, in this work, all the nanopores were fabricated by MPVI with voltages set at $V_{P1} = 7$ V, $V_{P2} = 2.5$ –3 V, and $V_R = 0.1$ V. The threshold current to verify the generation of the nanopore was set at 10 pA. These images confirm at a glance that only one nanopore was fabricated in the Si_3N_4 membrane (Figure 3a) and that nanopores with diameters less than 2 nm could be fabricated (Figures 3b–3e). Additional TEM images of nanopores larger (or smaller) than those observed in Figure 3 are presented in Supplementary Section SI-2, and the number of nanopores was one per membrane only. To determine the relation between the area of the nanopore and I_{Tot} at $V_R = 0.1$ V, the mean diameter of the nanopore (ϕ_m) can be approximated by an ellipsoidal approximation as

$$\phi_m = (\phi_1 \times \phi_s)^{1/2}, \quad (3)$$

where ϕ_1 and ϕ_s are the major and minor axes, respectively, of the nanopore measured from the TEM image. The dependence of ϕ_m on I_{Tot} at $V_R = 0.1$ V is illustrated in Figure 4. This figure shows that the mean diameter of the nanopore (down to 1 nm) can be precisely estimated by measuring I_{Tot} at $V_R = 0.1$ V. The plotted measure-

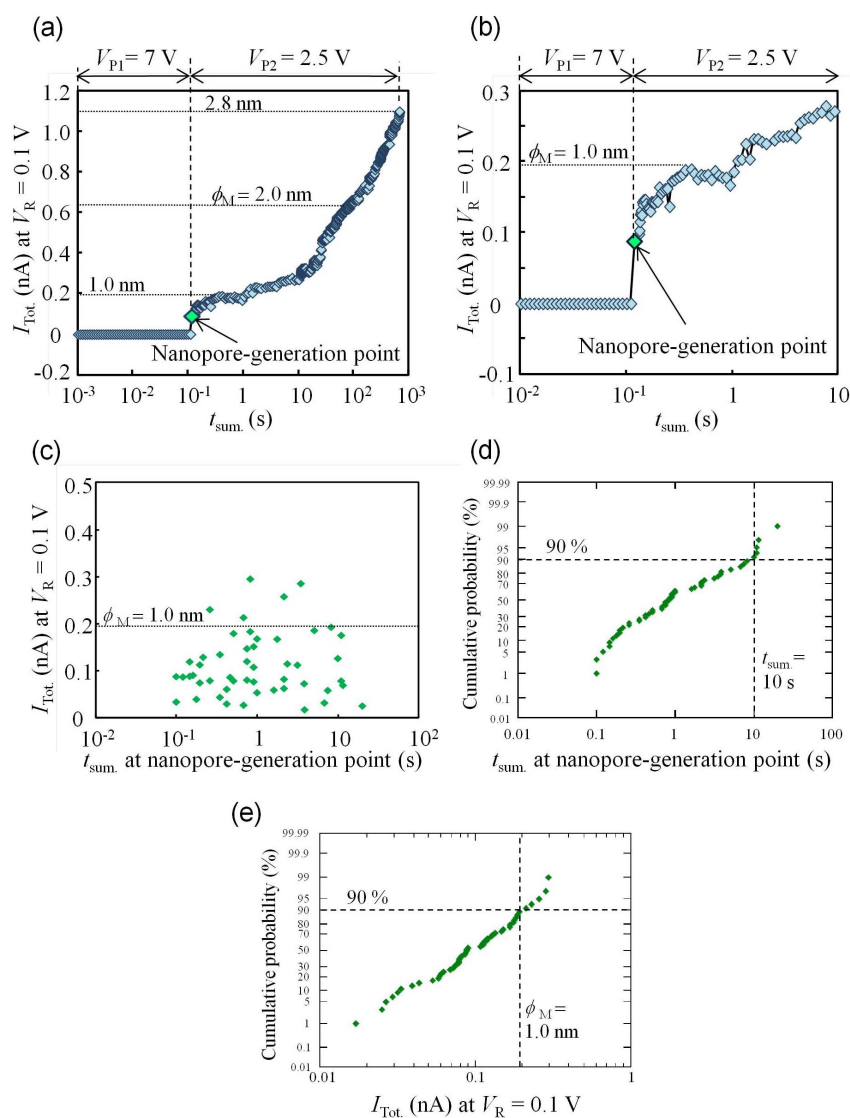


Figure 2 | Time-dependent characteristics of current (I_{Tot}) during MPVI. (a) Dependence of I_{Tot} at $V_R = 0.1$ V on the cumulative time of applied-pulse durations ($t_{\text{sum.}}$). A nanopore was generated at $t_{\text{sum.}} = 0.12$ s. (b) Magnified graph around the nanopore-generation point. (c) Scatter plot of I_{Tot} at $V_R = 0.1$ V and $t_{\text{sum.}}$ at the nanopore-generation point. (d) Cumulative probability of $t_{\text{sum.}}$ at the nanopore-generation point. (e) Cumulative probability of I_{Tot} at the nanopore-generation point.

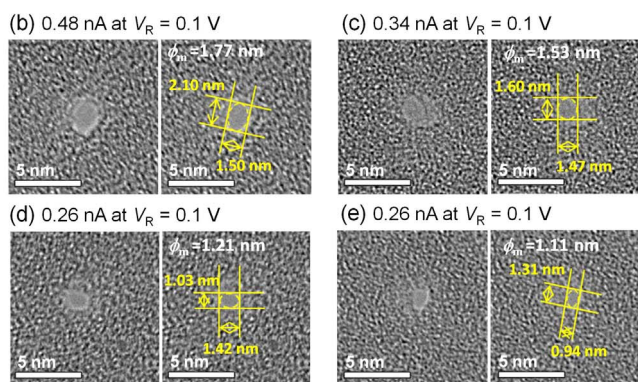
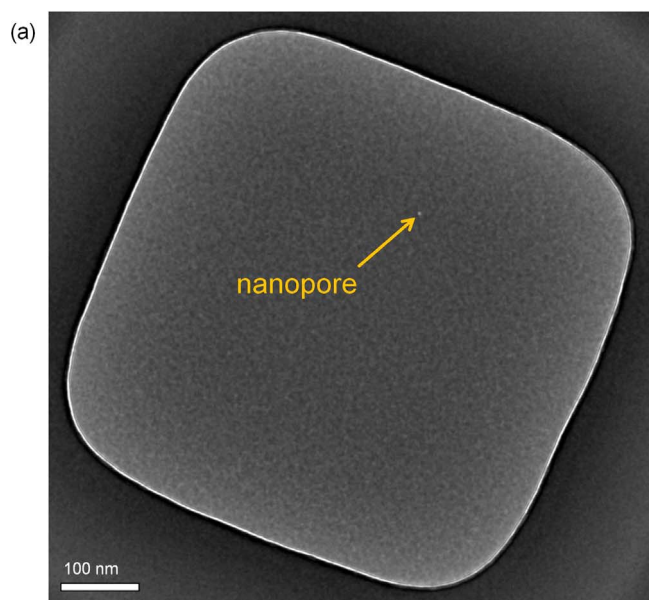


Figure 3 | TEM images of nanopores fabricated via MPVI. (a) Top view of the entire area of the thinnest part of the membrane (approximately $500 \times 500 \text{ nm}^2$ square and 10-nm-thick Si_3N_4 membrane) with the nanopore. Figure (c) is a magnified view of the nanopore shown in (a). (b)–(e) Magnified views of the nanopores. Each left image shows the raw image of each right image. The ionic currents through the nanopore (I_{Tot} at $V_R = 0.1 \text{ V}$) are (b) 0.48 nA, (c) 0.34 nA, (d) 0.26 nA, and (e) 0.25 nA.

ments agree well with the theoretically calculated lines obtained as follows^{13,32}:

$$I_{\text{Tot}} \approx I_{\text{NP}} = V_R \sigma \left(\frac{4h_{\text{eff}}}{\pi\phi_m^2} + \frac{1}{\phi_m} \right)^{-1}, \quad (4)$$

where h_{eff} is the effective height of the nanopore and $\sigma = 0.105 \text{ S/cm}$ is the measured conductance of the KCl buffer solution at 22.5°C . The calculation with h_{eff} of 3.7 nm is the central fitting line, and the variation in h_{eff} is small, within 3 to 4.5 nm. Accordingly, in this work, the mean diameters of the fabricated nanopores that were not observed by TEM were calculated from Equation (4) with $h_{\text{eff}} = 3.7 \text{ nm}$ and the measured I_{Tot} . To discriminate the calculated mean diameter from the mean diameter (ϕ_m) determined from the TEM images and Equation (3), another parameter, ϕ_M (which represents the diameter calculated from Equation (4) with $h_{\text{eff}} = 3.7 \text{ nm}$ and measured I_{Tot}), is introduced in the following. Notably, the mean h_{eff} of the nanopores fabricated with MPVI is approximately one-third of the actual membrane thickness (10 nm) and the mean h_{eff} of the nanopores generated by the TEM beam is also approximately one-third of the actual membrane thickness^{12,13}.

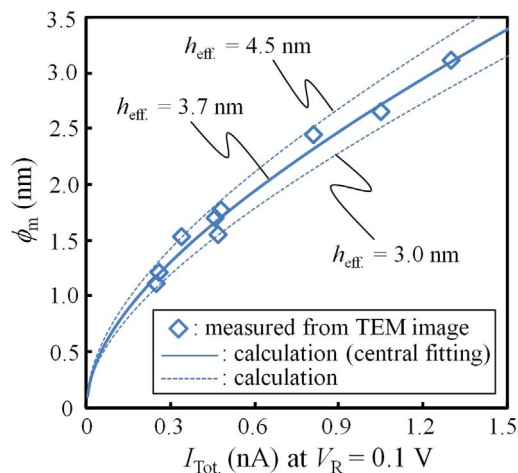


Figure 4 | Relation between the mean diameters (ϕ_m) of the fabricated nanopores and I_{Tot} at $V_R = 0.1 \text{ V}$. Nine points are plotted within $\phi_m = 1.11$ to 3.11 nm . The TEM images of all plotted points are presented in Figure 3 and Supplementary Section SI-2.

The characteristics observed in Figure 2 are reviewed in terms of the diameter ϕ_M as follows. A nanopore with ϕ_M of less than 1 nm could be generated and detected (as observed in Figures 2a and 2b). In addition, the generated nanopore could be widened to the intended size with sub-nanometre precision. A scatter plot of the cumulative pulse-duration time (t_{sum}) and I_{Tot} ($\sim I_{\text{NP}}$) at the nanopore-generation point (50 points are plotted) is presented in Figure 2c, and the cumulative probabilities of t_{sum} and I_{Tot} at the nanopore-generation point are plotted in Figures 2d and 2e, respectively. These figures illustrate that nanopores were rapidly generated within approximately $t_{\text{sum}} \leq 10 \text{ s}$ and that nanopores with diameters of less than 1 nm could be generated with a probability of 90%. These data demonstrate that nanopores with diameters of $< 1 \text{ nm}$ to 3 nm can be fabricated with sub-nanometre precision using MPVI.

ssDNA translocation through the nanopore. After the nanopore was fabricated using MPVI, the solution in the *cis* chamber was displaced by a 1 M KCl buffer solution with 1 nM 5.3-kb ss-poly(dA) without exposing the Si_3N_4 membrane to air. Details of the synthesis of 5.3-kb ss-poly(dA) are provided in the “Method” section. The ionic current through the nanopore was then measured at a voltage of 0.3 V (Figure 5). In the figure, ionic current blockades (ΔI) for each nanopore are observed, and each histogram of ΔI contains a discriminative peak (i.e., ΔI_p , calculated from Gaussian fits to each histogram), indicating ssDNA translocations through the nanopore. As ϕ_M decreased, the dwell times of ssDNA in the nanopore became long because of increases in the interactions between ssDNA and the nanopore¹⁶.

When $\phi_M \geq 1.2 \text{ nm}$, ssDNA-translocation events could be detected. When $\phi_M < 1.2 \text{ nm}$, the nanopore was clogged with ssDNA, and stable translocation events could not be detected (Supplementary Section SI-3). This threshold diameter is almost equal to the value reported by Venta *et al.*¹².

In addition, when $\phi_M < 2.0 \text{ nm}$, the frequency of ssDNA-translocation events strongly depended on the applied voltage. The frequency significantly decreased as the voltage was decreased from 0.3 to 0.1 V (see “Supplementary Section SI-4”); thus, statistical analysis of ΔI was difficult at 0.1 V. However, when $\phi_M > 2.5 \text{ nm}$, the discriminative peak did not appear in the histogram at 0.3 V, and ΔI_p was difficult to determine because the dwell times of ssDNA in the nanopore became shorter and the translocation events could not be measured accurately (see Supplementary Section SI-5). To detect the translocation events accurately with decreasing translocation speed

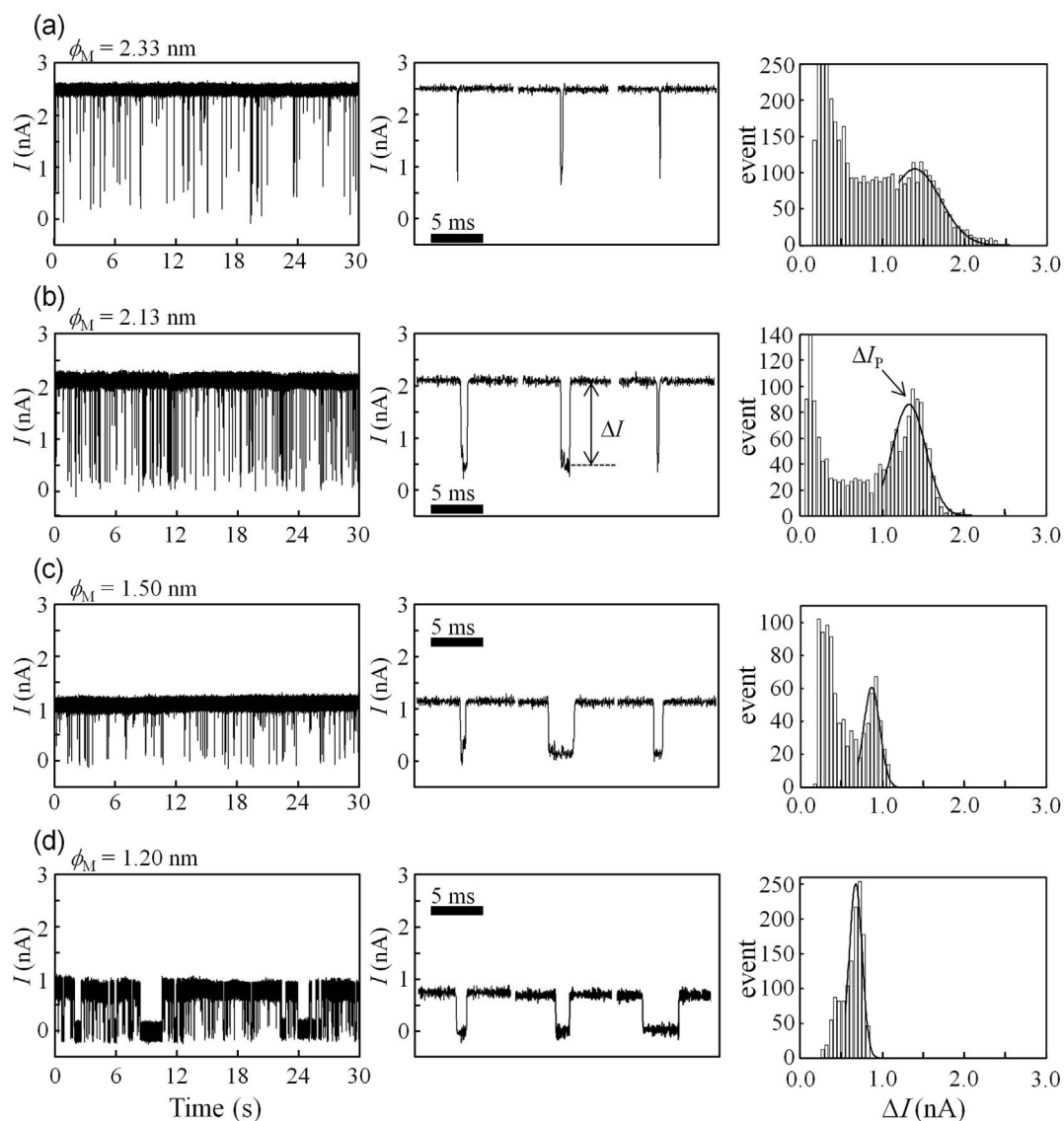


Figure 5 | Detections of ssDNA translocations through nanopores with different ϕ_M . The left figures show time traces of the ionic currents at 0.3 V. The middle figures are magnified views of the ionic-current blockades shown in the left figures. The right figures present histograms of the blockade currents (ΔI) with Gaussian-fit lines. ΔI_P was determined by the peak value of the Gaussian fit. Each data point was low-pass filtered at 10 kHz.

of ssDNA, the translocation events were detected, and ΔI_P was calculated at 0.1 V for $\phi_M > 2.5$ nm.

The dependence of ΔI_P on $I_{T_{\text{tot}}}$ (open-nanopore current) is illustrated in Figure 6. ΔI_P and $I_{T_{\text{tot}}}$ were normalised at 0.1 V; i.e., ΔI_P and $I_{T_{\text{tot}}}$ at 0.3 V and $\phi_M < 2.5$ nm were measured and divided by three (because ΔI_P and $I_{T_{\text{tot}}}$ are proportional to the applied voltage, as explained in Supplementary Section SI-4). When $I_{T_{\text{tot}}}$ was large (i.e., greater than 0.7 nA; $\phi_M > 2.1$ nm, which is sufficiently larger than the diameter of ssDNA), ΔI_P was almost constant; i.e., the range of ΔI_P was 0.39 to 0.47 nA and the average value of ΔI_P was 0.44 nA, which corresponds to a ϕ_M of 1.62 nm. This value is reasonable because a ϕ_M of 1.62 nm fairly closely agrees with the diameter of ssDNA (approximately 1.4 nm). When $\phi_M < 1.62$ nm, the value of $\Delta I_P/I_{T_{\text{tot}}}$ approached one and ΔI_P tended to be constrained by $I_{T_{\text{tot}}}$, suggesting that the diameter of ssDNA might decrease to fit the diameter of the given nanopore.

Discussion

The proposed technique, called multilevel pulse-voltage injection (MPVI), was demonstrated to precisely and simply fabricate

nanopores with diameters of 1 to 2 nm, which are essential sizes for distinguishing each nucleotide. MPVI is an iteration sequence that involves of the application high-voltage pulses (V_{P1}) to generate or widen a nanopore and measurement of an electrical current between the electrodes ($I_{T_{\text{tot}}}$) at low voltage (V_R) to verify whether the nanopore has been generated. When V_{P1} was set to 7 V, a nanopore could be rapidly generated (within approximately 10 seconds in the cumulated pulse-durations (t_{sum})) in a 10-nm-thick Si_3N_4 membrane. A nanopore could be generated with a diameter of less than 1 nm with a probability of 90% when a set of narrow-width pulses were used, i.e., then the number of the applied pulses per decade of time was 24. The diameter of the nanopore (down to sub-1 nm) could be estimated from $I_{T_{\text{tot}}}$ because the trap-assisted tunnelling current through the membrane could be ignored ($I_{T_{\text{AT}}} \sim 0$) at low voltage ($V_R = 0.1$ V). After the nanopore was generated, its size could be adjusted to the desired size with sub-nanometre precision via the application of mid-voltage pulses ($V_{P2} = 2.5\text{--}3$ V). We thus concluded that, compared to the conventional technique of using a focused-electronic beam via TEM, MPVI enables the easy, rapid, and highly accurately fabrication of a nanopore. TEM observations

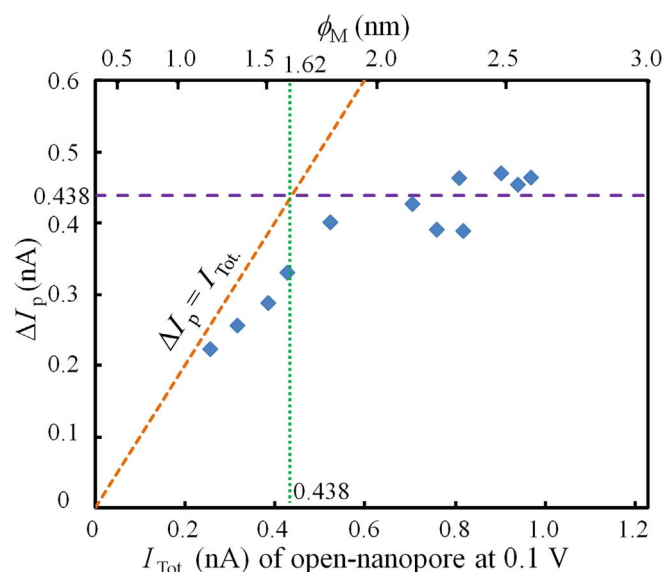


Figure 6 | Dependence of ΔI_p on the I_{Tot} (nA) of open nanopores at 0.1 V. The purple horizontal line represents the average value of ΔI_p for $\phi_M > 2.1$ nm (seven points). The sloping orange line represents $\Delta I_p = I_{Tot}$ (which represents an asymptote of the plots when $\phi_M < 1.62$ nm).

of the nanopores fabricated by MPVI indicated that the relation between I_{Tot} and ϕ_m within a ϕ_m range of 1 to 3 nm was well explained theoretically, specifically, by Equation (4), with a mean $h_{eff} = 3.7$ nm. This result demonstrates that ϕ_m can be monitored with sub-nanometre precision through the measurement of I_{Tot} . Moreover, ssDNA translocations through the nanopores fabricated by MPVI were successfully demonstrated. We observed that the value of $\Delta I_p/I_{Tot}$ approached one when $\phi_M < 1.62$ nm, which is approximately the same diameter as that of ssDNA. This result also indicates that nanopores with diameters of 1–2 nm can be precisely fabricated by MPVI. We thus conclude that MPVI is a promising approach for realising the practical use of solid-state nanopores.

Methods

Fabrication of membranes. First, 10-nm-thick Si_3N_4 membranes (with areas restricted within small (500×500 nm²) square areas such that the fabricated nanopore could be easily found) were prepared. The membranes were fabricated on an 8-inch silicon wafer with a thickness of 725 μ m. First, a multilayer of $Si_3N_4/SiO_2/Si_3N_4$ (12/250/100 nm) was deposited onto the front of the wafer, and a Si_3N_4 layer with a thickness of 112 nm was deposited onto the backside of the wafer. The top Si_3N_4 layer in each 500×500 nm² square area and the backside Si_3N_4 layer in each corresponding 1038×1038 μ m² square area were subsequently etched by reactive-ion etching, followed by silicon-substrate etching with TMAH (tetramethylammonium hydroxide). The front surface of the wafer was coated with protective films (ProTEK®B3primer and ProTEK®B3, Brewer Science, Inc.) during the silicon-substrate etching. The protection film was removed by acetone after the silicon-substrate etching. Finally, the SiO_2 layer in each 500×500 nm² square area was removed with buffered hydrofluoric acid (BHF: HF:NH₄F = 1:60 for 8 min) and thin- Si_3N_4 -membrane portions with thicknesses of 10 nm were fabricated. The thickness of the bottom Si_3N_4 layer was reduced by 2 nm during the etching with BHF. Before the MPVI method was applied, the membranes were cleaned and hydrophilised on each side with argon/oxygen plasma (SAMCO, Inc., Japan) at 10 W, a flow rate of 20 sccm, and a pressure of 20 Pa for 45 s.

Materials. Single-stranded poly(dA) was prepared by DNA synthesis reactions in two steps. In the first step, the reaction mixture contained $1 \times$ buffer for KOD Plus Ver. 2, 0.2-mM dATP, 0.2-mM dTTP, 1.5-mM MgSO₄, 0.3- μ M dA20 primer (5'-(dA)₂₀-3'), 0.3- μ M dT45 primer (5'-(dT)₄₅-3'), and 0.02-U/ μ L KOD Plus Ver. 2 polymerase (TOYOBO, Japan). The first reaction was performed using the following amplification process: denaturation at 94°C for 2 min, 45 cycles of denaturation at 94°C for 15 s, primer annealing at 60°C for 30 s, and extension at 68°C for 10 min. The reaction mixture was then purified with a QIAquick PCR purification kit (QIAGEN, Germany) and was subsequently dissolved in Buffer EB (5-mM Tris-HCl at pH 8.5) to obtain the first reaction product, i.e., complementary strands of poly(dA)-poly(dT) (ds-poly(dA)-poly(dT)). In the second step, the reaction mixture contained $1 \times$ Ex Taq Buffer, 0.8-mM dATP, 0.5- μ M dA20 primer, 5.0-ng/ μ L of the

first reaction product, and 0.025-U/ μ L Ex Taq polymerase. The second reaction was performed using the following amplification process: denaturation at 94°C for 2 min, 45 cycles of denaturation at 94°C for 15 s, primer annealing at 30°C for 30 s, and extension at 72°C for 15 min. The reaction mixture was then purified with a QIAquick PCR purification kit and was dissolved in Buffer EB to obtain the second reaction product, i.e., ss-poly(dA). The lengths of the first (ds-poly(dA)-poly(dT)) and second (ss-poly(dA)) reaction products were estimated to be 5.5 ± 0.9 kbp and 5.3 ± 0.4 kb (average \pm standard deviation), respectively, using alkaline-agarose-gel electrophoresis. Further details about the evaluation of the prepared ss-poly(dA) are provided elsewhere³³.

Observations of the fabricated nanopores by TEM. The fabricated nanopores were observed with a field-emission transmission electron microscope (JEM-2100F(HRP), 200 keV, JEOL, Ltd.). Before the observations, the membranes were immersed in warm DI water (32°C) for more than a day to remove any salt residues.

Setup for MPVI and detection and analysis of ssDNA-translocation events. The prepared membrane was first mounted onto a custom-built acrylic flowcell. Separated by the membrane, two chambers (each with a volume of 90 μ L) were formed in the flowcell: a *cis* chamber and a *trans* chamber. Both chambers were filled with a buffer solution consisting of 1 M potassium chloride, 10 mM Tris-HCl, and 1 mM EDTA buffer at pH 7.5. An Ag/AgCl electrode was immersed into each solution to assure electrical contact between the chambers.

The pulse voltages used in the MPVI were applied with a 41501B SMU AND Pulse Generator Expander (Agilent Technologies, Inc.), and the electrical currents between the electrodes were measured with a 4156B PRECISION SEMICONDUCTOR ANALYZER (Agilent Technologies, Inc.). The MPVI procedure was controlled by a programme written in Excel VBA (Visual Basic for Applications). Further information on the procedure is provided in Supplementary Section SI-1.

To detect ssDNA translocation events, a patch-clamp amplifier (Axopatch 200B, Axon Instruments, Union City, CA) was used to apply voltages and to detect the ionic current through the nanopores. The detected current was first low-pass filtered through a four-pole Bessel filter with a cutoff frequency of 10 kHz, then digitised with an NI USB-6281 18-bit DAQ AD converter (National Instruments, Austin, TX) at 50 kHz, and subsequently recorded onto the hard disk of a personal computer. Current-blockade events were identified and analysed using the Clampfit 10.2 software (Molecular Devices). The entire previously described procedure was performed at room temperature.

1. Branton, D. *et al.* The potential and challenges of nanopore sequencing. *Nat. Biotech.* **26**, 1146–1153 (2008).
2. Clarke, J. *et al.* Continuous base identification for single-molecule nanopore DNA sequencing. *Nat. Nanotechnol.* **4**, 265–270 (2009).
3. Derrington, I. M. *et al.* Nanopore DNA sequencing with MspA. *Proc. Natl. Acad. Sci. USA* **107**, 37, 16060–16065 (2010).
4. Manrao, E. A. *et al.* Reading DNA at single-nucleotide resolution with a mutant MspA nanopore and phi29 DNA polymerase. *Nat. Biotech.* **30**, 349–353 (2012).
5. Cherf, G. M. *et al.* Automated forward and reverse ratcheting of DNA in a nanopore at 5-A precision. *Nat. Biotech.* **30**, 344–348 (2012).
6. Ayub, M. & Bayley, H. Individual RNA base recognition in immobilized oligonucleotides using a protein nanopore. *Nano Lett.* **12**, 5637–5643 (2012).
7. Venkatesan, B. M. & Bashir, R. Nanopore sensors for nucleic acid analysis. *Nat. Nanotechnol.* **6**, 615–624 (2011).
8. Zwolak, M. & Di Ventra, M. Colloquium: Physical approaches to DNA sequencing and detection. *Rev. Mod. Phys.* **80**, 141–165 (2008).
9. Ohshiro, T. *et al.* Single-molecule electrical random resequencing of DNA and RNA. *Sci. Rep.* **2**, 501; DOI:10.1038/srep00501 (2012).
10. Xie, P., Xiong, Q., Fang, Y., Qing, Q. & Lieber, C. M. Local electrical potential detection of DNA by nanowire-nanopore sensors. *Nat. Nanotechnol.* **7**, 119–125 (2012).
11. Yanagi, I. *et al.* A novel side-gated ultrathin-channel nanopore FET (SGNAFET) sensor for direct DNA sequencing. *IEDM Tech. Dig.* 14.3.1–14.3.4 (2013).
12. Venta, K. *et al.* Differentiation of short, single-stranded DNA homopolymers in solid-state nanopores. *ACS Nano* **7**, 4629–4636 (2013).
13. Wanunu, M. *et al.* Rapid electronic detection of probe-specific microRNAs using thin nanopore sensors. *Nat. nanotechnol.* **5**, 807–814 (2010).
14. Larkin, J. *et al.* Slow DNA transport through nanopores in hafnium oxide membrane. *ACS Nano* **7**, 11, 10121–10128 (2013).
15. Smeets, R. M. M. *et al.* Salt dependence of ion transport and DNA translocation through solid-state nanopores. *Nano Lett.* **6**, 89–95 (2006).
16. Wanunu, M., Sutin, J., McNally, B., Chow, A. & Meller, A. DNA translocation governed by interactions with solid-state nanopores. *Biophys. J.* **95**, 4716–4725 (2008).
17. Rosenstein, J. K., Wanunu, M., Merchant, C. A., Drndic, M. & Shepard, K. L. Integrated nanopore sensing platform with sub-microsecond temporal resolution. *Nat. method* **9**, 487–492 (2012).
18. Garaj, S. *et al.* Graphene as a sub-nanometer trans-electrode membrane. *Nature* **467**, 190–193 (2010).
19. Garaj, S., Liu, S., Golovchenko, J. A. & Branton, D. Molecule-hugging graphene nanopores. *Proc. Natl. Acad. Sci. USA* **110**, 30, 12192–12196 (2013).



20. Schneider, G. F. *et al.* DNA translocation through graphene nanopores. *Nano Lett.* **10**, 3163–3167 (2010).
21. Merchant, C. A. *et al.* DNA translocation through graphene nanopores. *Nano Lett.* **10**, 2915–2921 (2010).
22. Sathe, C., Zou, X., Leburton, J. P. & Schulten, K. Computational investigation of DNA detection using graphene nanopores. *ACS Nano* **5**, 11, 8842–8851 (2011).
23. Wells, D. B., Belkin, M., Comer, J. & Aksimentiev, A. Assessing graphene nanopores for sequencing DNA. *Nano Lett.* **12**, 4117–4123 (2012).
24. Storm, A. J., Chen, J. H., Ling, X. S., Zandbergen, H. W. & Dekker, C. Fabrication of solid-state nanopores with single-nanometre precision. *Nat. Mater.* **2**, 537–540 (2003).
25. Jiang, Z., Mihovilovic, M., Chan, J. & Stein, D. Fabrication of nanopores with embedded annular electrodes and transverse carbon nanotube electrodes. *J. Phys.: Condens. Matter* **22**, 454114–454124 (2010).
26. Kwok, H., Briggs, K. & Tabard-Cossa, V. Nanopore fabrication by controlled dielectric breakdown. *Cond. Mat.* arXiv,1310.5126 (2013).
27. Beamish, E., Kwok, H., Tabard-Cossa, V. & Godin, M. Precise control of the size and noise of solid-state nanopores using high electric fields. *Nanotechnology* **23**, 405301 (2012).
28. Tewhey, R., Bansal, V., Torkamani, A., Topol, E. J. & Schork, N. J. The importance of phase information for human genomics. *Nat. Rev. Genet.* **12**, 215–223 (2011).
29. Ma, T. P. Making silicon nitride film a viable gate dielectric. *IEEE Trans. Electron Devices.* **45**, 680–690 (1998).
30. Frenkel, J. On Pre-Breakdown phenomena in insulators and electronic semi-conductors. *Phys. Rev.* **54**, 647–648 (1938).
31. Kimura, M. & Ohmi, T. Conduction mechanism and origin of stress-induced leakage current in thin silicon dioxide films. *J. Appl. Phys.* **80**, 6360–6369 (1996).
32. Hall, J. E. Access resistance of a small circular pore. *J. Gen. Physiol.* **66**, 531–532 (1975).
33. Akahori, R. *et al.* Slowing single-stranded DNA translocation through a solid-state nanopore by decreasing nanopore diameter. *Nanotechnology*, accepted (2014).

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Author contributions

I.Y. developed the initial concept. I.Y. and R.A. proved the feasibility of the concept. I.Y. and R.A. designed and performed experiments and analysed the data. T.H. and R.A. prepared ssDNA. K.T. supervised the study.

Additional information

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